

Phase Control Thyristor

DS6048-1 April 2011 (LN28259)

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- High Power Drives
- High Voltage Power Supplies
- Static Switches

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{DRM} and V _{RRM} V	Conditions
DCR610D34 DCR610D32 DCR610D30 DCR610D28 DCR610D26 DCR610D24	3400 3200 3000 2800 2600 2400	$\begin{split} T_{vj} &= -40^{\circ}\text{C to } 125^{\circ}\text{C}, \\ I_{DRM} &= I_{RRM} = 50\text{mA}, \\ V_{DRM}, V_{RRM} t_p &= 10\text{ms}, \\ V_{DSM} \& V_{RSM} &= \\ V_{DRM} \& V_{RRM} +100V \\ respectively \end{split}$

Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DCR610D34

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

KEY PARAMETERS

3400 V
610 A
8000 A
1000 V/μs
150 A/μs

* Higher dV/dt selections available

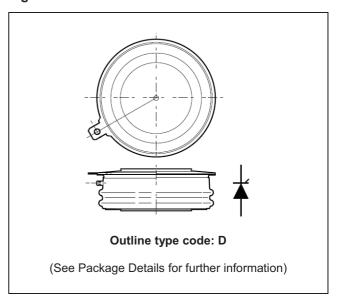


Fig. 1 Package outline



CURRENT RATINGS

T_{case} = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			
I _{T(AV)}	Mean on-state current	Half wave resistive load	610	А
I _{T(RMS)}	RMS value	-	960	А
I _T	Continuous (direct) on-state current	-	860	А

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{TSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 125°C	8.0	kA
l ² t	I ² t for fusing	V _R = 0	0.32	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.035	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Double side cooled	DC	1	0.01	°C/W
T_{vj}	Virtual junction temperature	Blocking V _{DRM} / _{VRRM}		-	125	°C
T _{stg}	Storage temperature range			-40	140	°C
F _m	Clamping force			8	12	kN



DYNAMIC CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
I _{RRM} /I _{DRM}	Peak reverse and off-state current	At V _{RRM} /V _{DRM} , T _{case} = 125°C		-	50	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V _{DRM} , T _j = 125°C, ga	ate open	1000	-	V/µs
dl/dt	Rate of rise of on-state current	From 67% V _{DRM} to 1000A	Repetitive 50Hz	-	150	A/µs
		Gate source 30V, 10Ω,	Non-repetitive	-	1000	A/µs
		t _r < 0.5µs, T _j = 125°C				
V _T	On-state voltage	I _T = 1500A, T _{case} = 125°C			2.78	V
V _{T(TO)}	Threshold voltage	T _{case} = 125°C		-	0.98	V
r _T	On-state slope resistance	T _{case} = 125°C		-	1.20	mΩ
t _{gd}	Delay time	V_D = 67% V_{DRM} , gate source 30V, 10Ω		-	3.0	μs
	,	$t_r = 0.5 \mu s, T_j = 25^{\circ}C$				
IL	Latching current	T _j = 25°C,		-	1	Α
I _H	Holding current	T _j = 25°C,		-	200	mA

GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V_{GT}	Gate trigger voltage	V _{DRM} = 5V, T _{case} = 25°C	3	V
V_{GD}	Gate non-trigger voltage	At 40% V _{DRM} , T _{case} = 125°C	TBD	V
I _{GT}	Gate trigger current	V _{DRM} = 5V, T _{case} = 25°C	300	mA
I _{GD}	Gate non-trigger current	At 40% V _{DRM} , T _{case} = 125°C	TBD	mA



CURVES

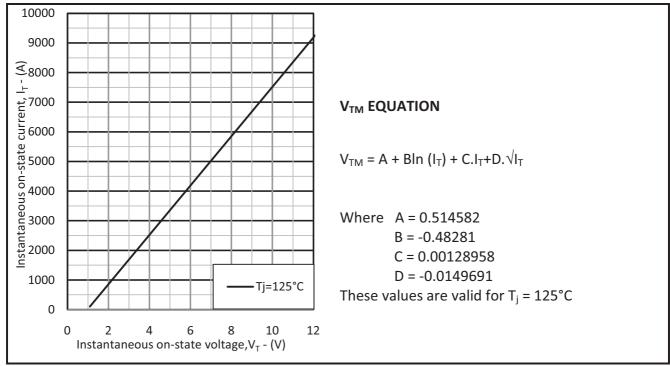


Fig.2 Maximum &minimum on-state characteristics

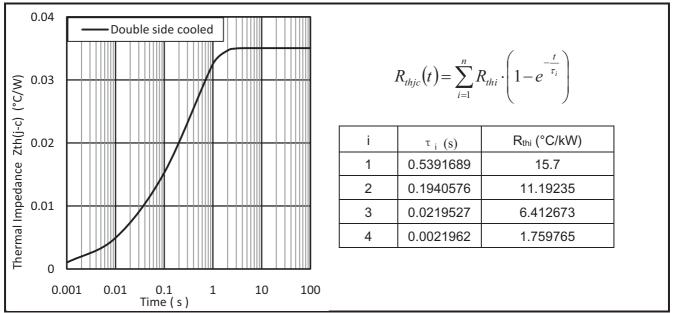
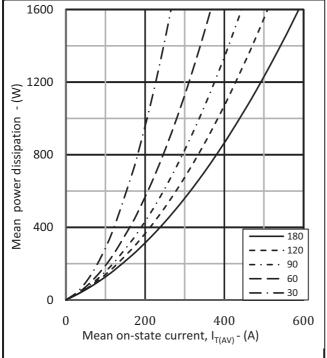
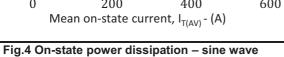


Fig.3 Maximum (limit) transient thermal impedance – junction to case (°C/W)







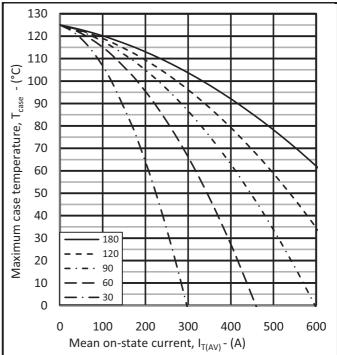


Fig.5 Maximum permissible case temperature, double side cooled - sine wave

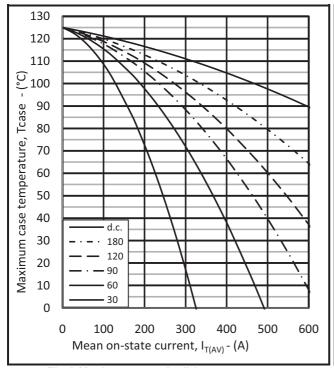


Fig.6 Maximum permissible case temperature, double side cooled - rectangular wave

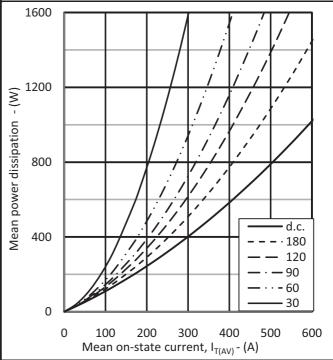
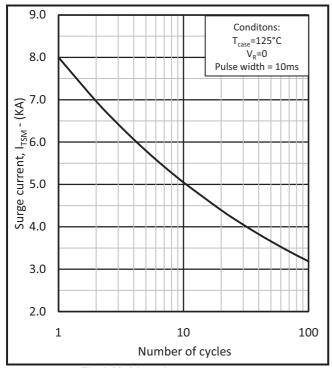
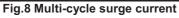


Fig.7 On-state power dissipation - rectangular wave





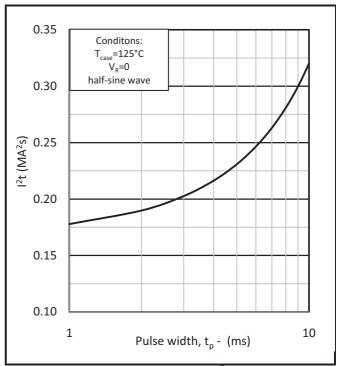


Fig.9 Single-cycle I²t

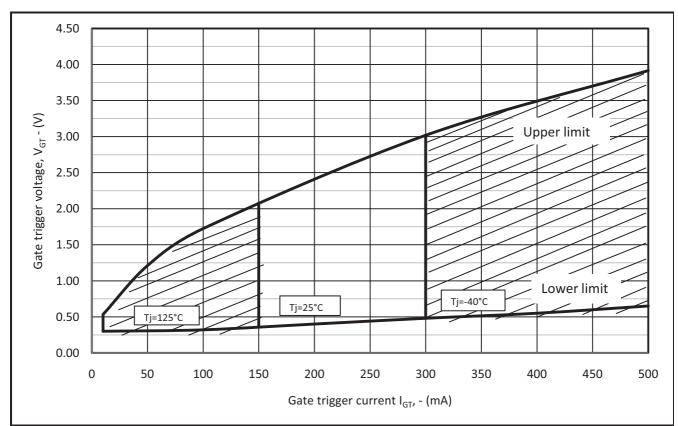


Fig.10 Gate characteristics

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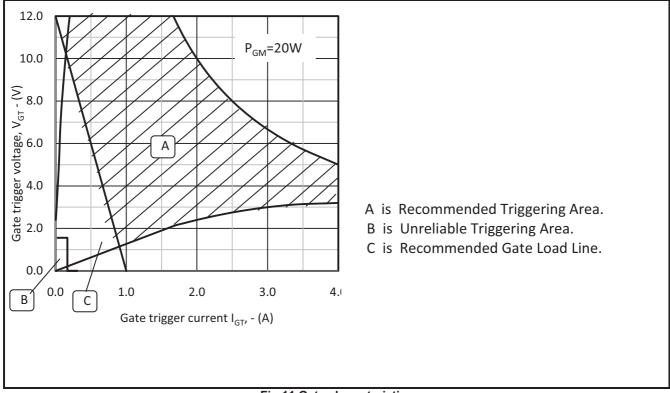


Fig.11 Gate characteristics



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

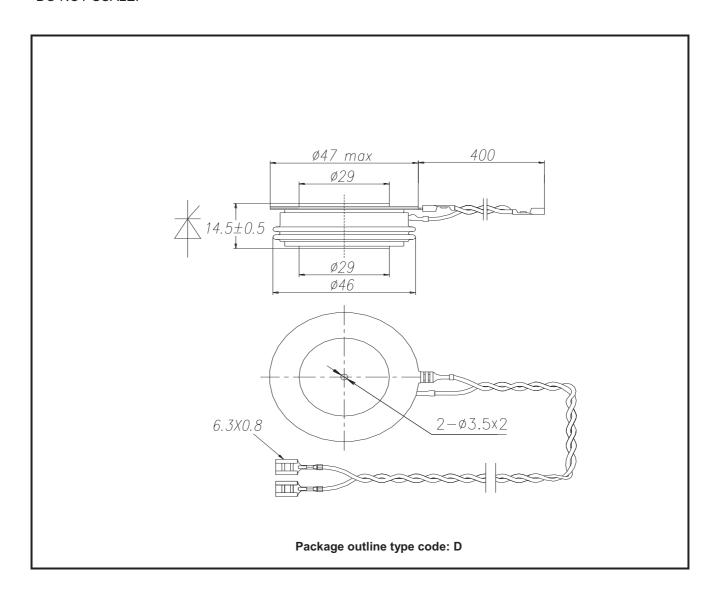


Fig.12 Package outline



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No actual design work on the product has been started.

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